

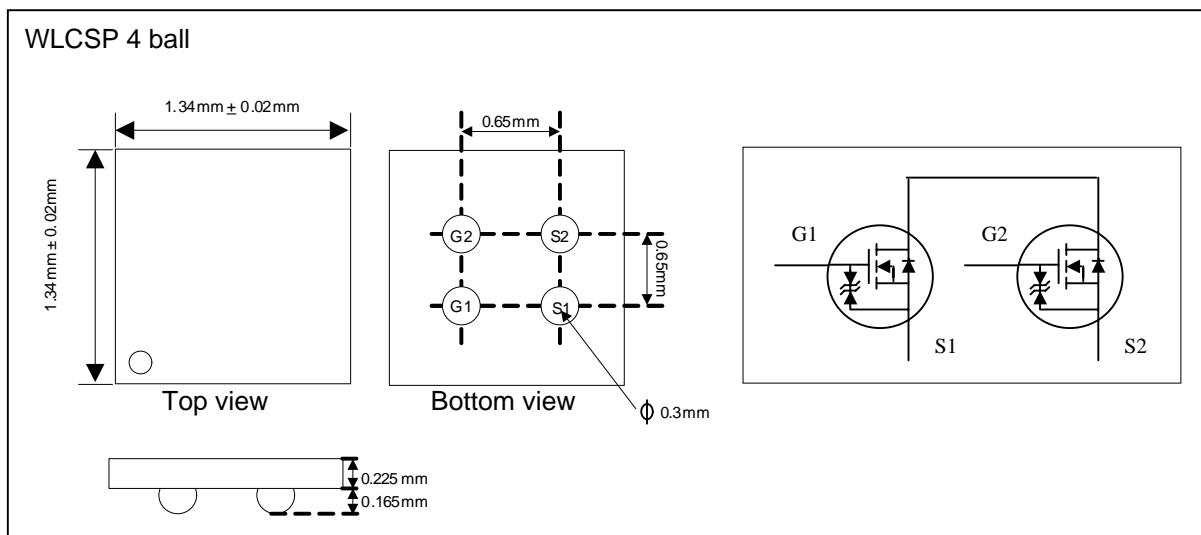


- ▼ Capable of 2.5V Gate Drive
- ▼ Ultra-small Package Outline
- ▼ Protection Diode Built-in
- ▼ RoHS Compliant & Halogen-Free

V_{SSS}	24V
$R_{SS(ON)}$	38mΩ
I_S	6A

Description

AP2904 series are from Advanced Power innovated design and silicon process technology to achieve the lowest possible on-resistance and fast switching performance. It provides the designer with an extreme efficient device for the load switch, charge switch, battery switch for portable application.



Absolute Maximum Ratings@ $T_j=25^\circ\text{C}$ (unless otherwise specified)

Symbol	Parameter	Rating	Units
V_{SSS}		24	V
V_{GSS}		± 12	V
I_S	Source Current ³	6	A
I_{SM}	Pulsed Source Current ¹	45	A
$P_D @ T_A=25^\circ\text{C}$	Total Power Dissipation ³	1.25	W
T_{STG}	Storage Temperature Range	-55 to 150	°C
T_J	Junction Temperature	-55 to 150	°C



Electrical Characteristics@ $T_j=25^\circ\text{C}$ (unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Typ.	Max.	Units
$V(BR)_{SSS}$	Source-Source Breakdown Voltage	$V_{GS}=0\text{V}, I_S=250\mu\text{A}$	24	-	-	V
$R_{SS(ON)}$	Static Source-Source On-Resistance ²	$V_{GS}=4.5\text{V}, I_S=1\text{A}$	23	29	38	$\text{m}\Omega$
		$V_{GS}=4\text{V}, I_S=1\text{A}$	24	30	39	$\text{m}\Omega$
		$V_{GS}=3.1\text{V}, I_S=1\text{A}$	26	33	44	$\text{m}\Omega$
		$V_{GS}=2.5\text{V}, I_S=1\text{A}$	30	37	49	$\text{m}\Omega$
$V_{GS(\text{off})}$	Cutoff Voltage	$V_{SS}=10\text{V}, I_S=1\text{mA}$	0.4	-	1.3	V
$ y_{fs} $	Forward Transfer Admittance	$V_{SS}=5\text{V}, I_S=2.25\text{A}$	-	15	-	S
I_{SSS}	Zero Gate Voltage Source Current	$V_{SS}=20\text{V}, V_{GS}=0\text{V}$	-	-	10	μA
I_{GSS}	Gate-Source Leakage Current	$V_{GS}=\pm 12\text{V}, V_{SS}=0\text{V}$	-	-	± 30	μA
$t_{d(on)}$	Turn-on Delay Time	$V_{SS}=20\text{V}$ $I_S=2.25\text{A}$	-	1	-	us
t_r	Rise Time		-	5	-	us
$t_{d(off)}$	Turn-off Delay Time		-	12	-	us
t_f	Fall Time		-	8	-	us
Q_g	Total Gate Charge	$V_{SS}=20\text{V}, V_{GS}=4\text{V}, I_S=4.5\text{A}$	-	13	-	nC
$V_{F(S-S)}$	Forward Source-Source Voltage ²	$I_S=1.5\text{A}, V_{GS}=0\text{V}$	-	-	1.2	V

Notes:

- 1.Pulse width limited by Max. junction temperature.
- 2.Pulse test
- 3.Surface mounted on 1 in² 2oz copper pad of FR4 board, $t \leq 5\text{s}$

THIS PRODUCT IS SENSITIVE TO ELECTROSTATIC DISCHARGE, PLEASE HANDLE WITH CAUTION.

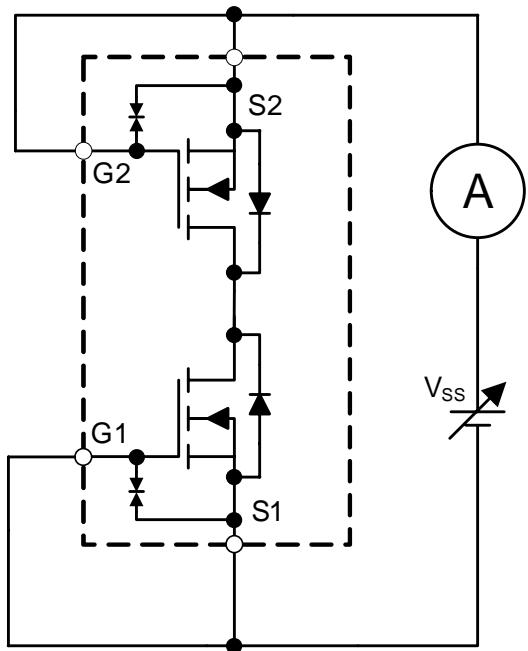
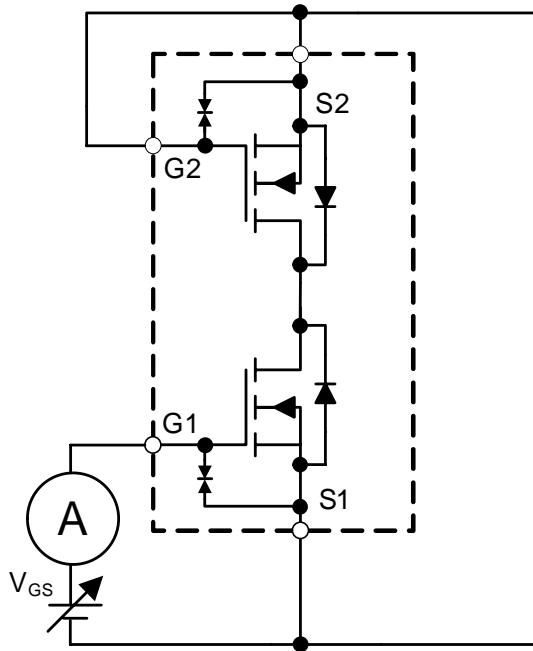
USE OF THIS PRODUCT AS A CRITICAL COMPONENT IN LIFE SUPPORT OR OTHER SIMILAR SYSTEMS IS NOT AUTHORIZED.

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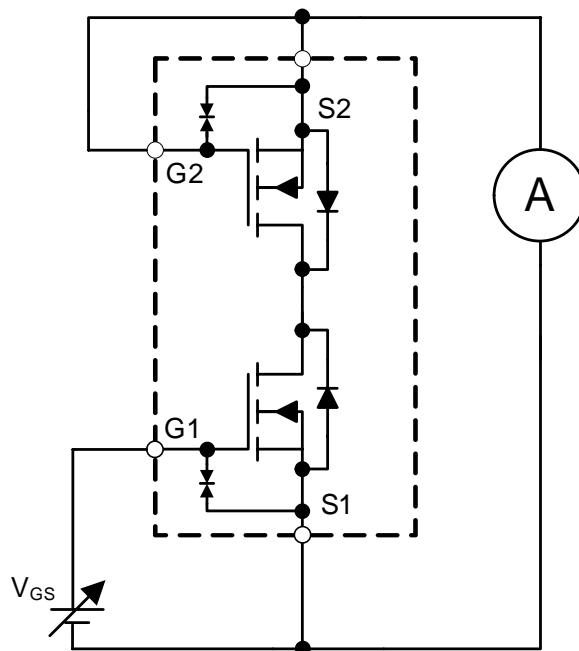
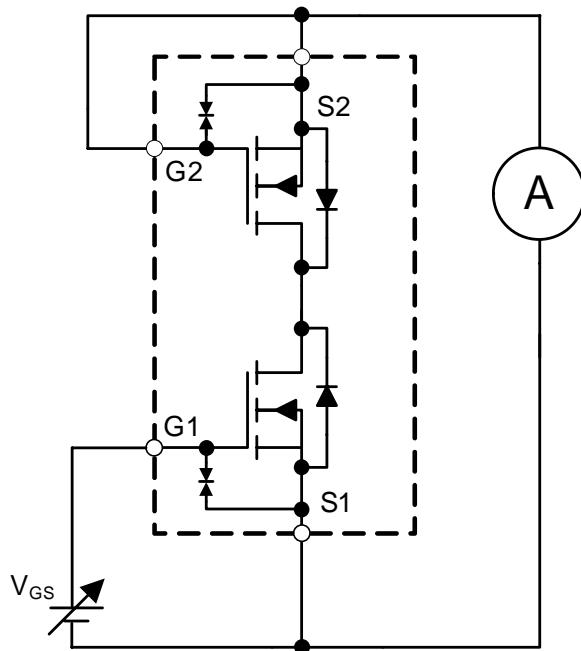
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**Test Circuits are Example of Measuring Channel-1 (unless otherwise specified)**

When Ch-1 is measured, Gate and Source of Ch-2 are short-circuited.

**TEST CIRCUIT : I_{SSS}** **TEST CIRCUIT : I_{GSS}**

When Ch-1 is measured, Gate and Source of Ch-2 are short-circuited.

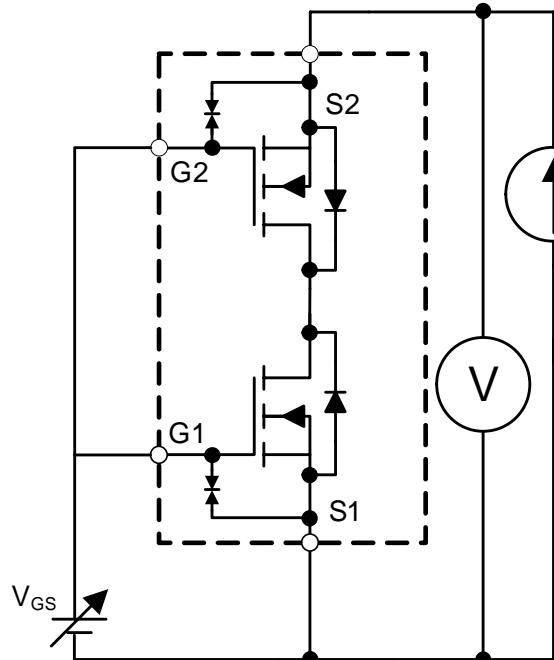
**TEST CIRCUIT : $V_{GS(\text{off})}$** **TEST CIRCUIT : $|y_{fs}|$**



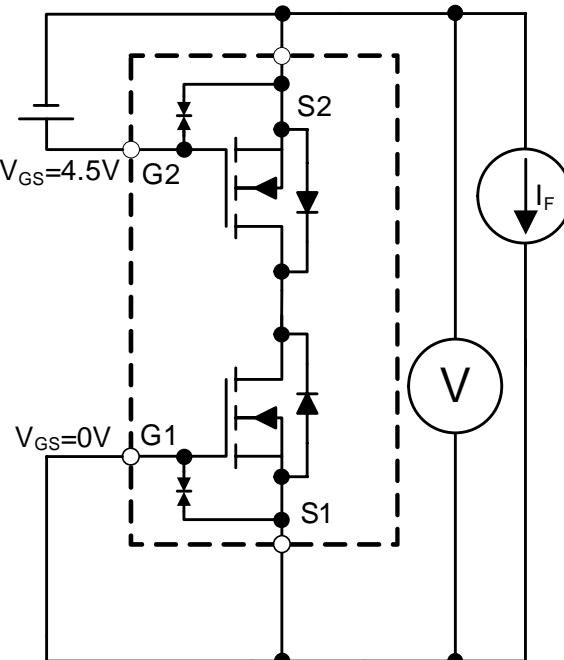
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Test Circuits are Example of Measuring Channel-1 (unless otherwise specified)

When Ch-1 is measured, +4.5V
is added to V_{GS} of Ch-2

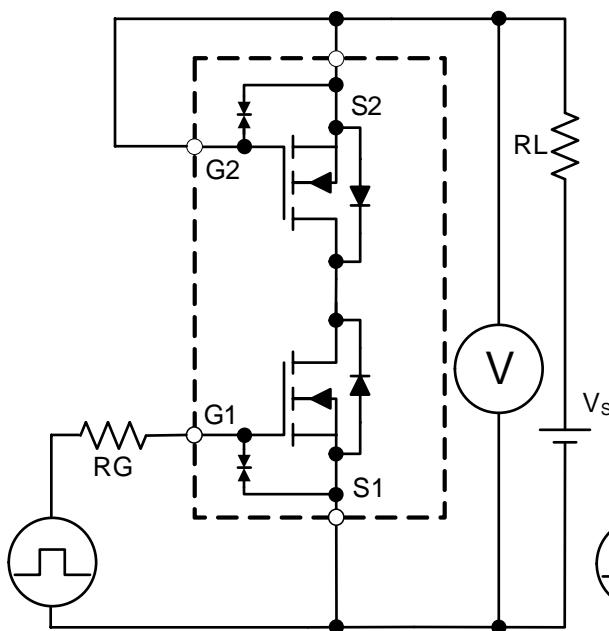


TEST CIRCUIT : $R_{SS(ON)}$



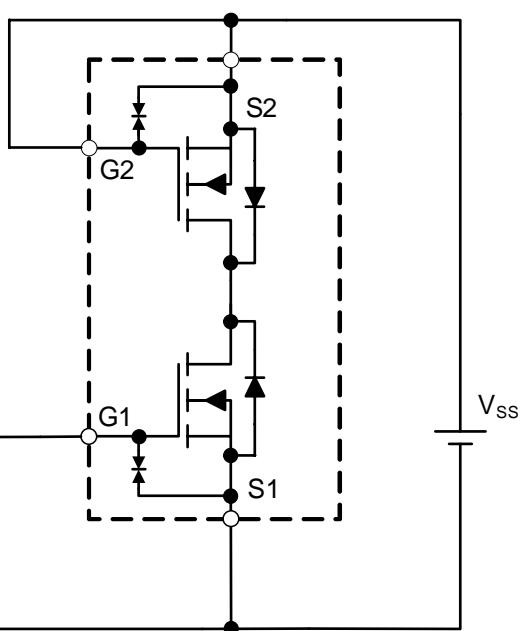
TEST CIRCUIT : $V_{F(s-s)}$

When Ch-1 is measured, Gate
and Source of Ch-2 are short-
circuitd.



TEST CIRCUIT : Switching Time

When Ch-1 is measured, Gate
and Source of Ch-2 are short-
circuitd.



TEST CIRCUIT : Gate Charge

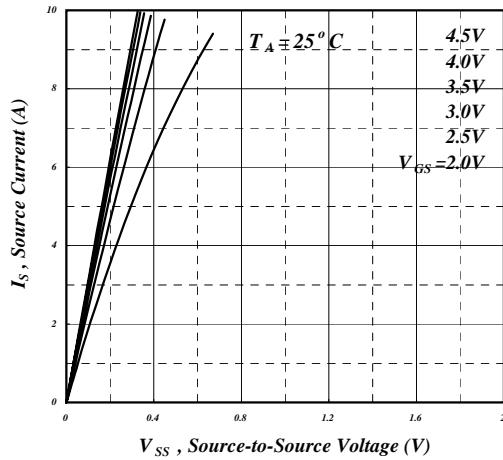


Fig 1. Typical Output Characteristics

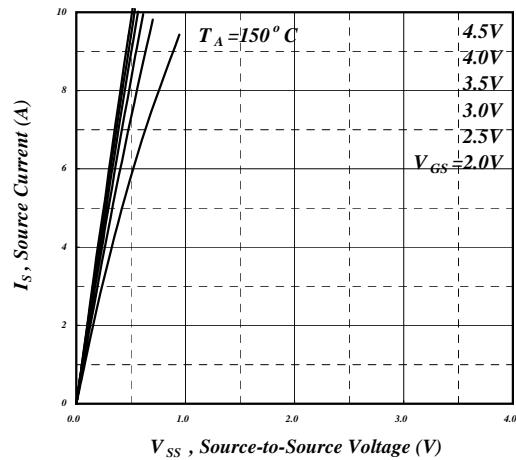


Fig 2. Typical Output Characteristics

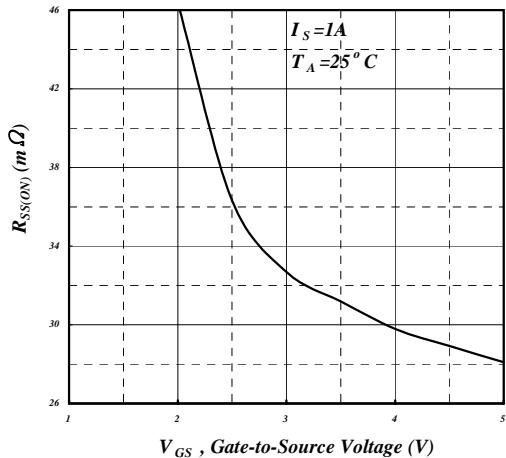


Fig 3. Static Source-to-Source On-Resistance v.s. Gate Voltage

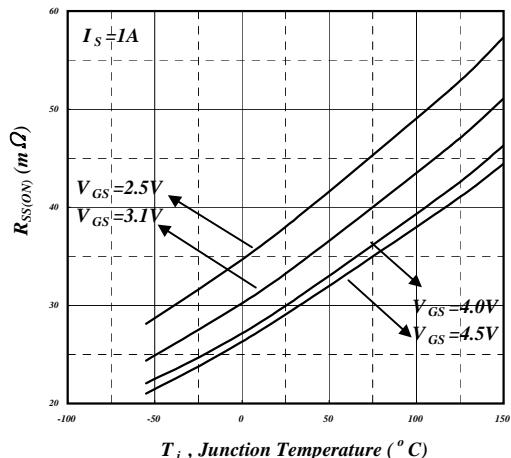


Fig 4. Typ. Source-to-Source on State Resistance v.s. Junction Temperature

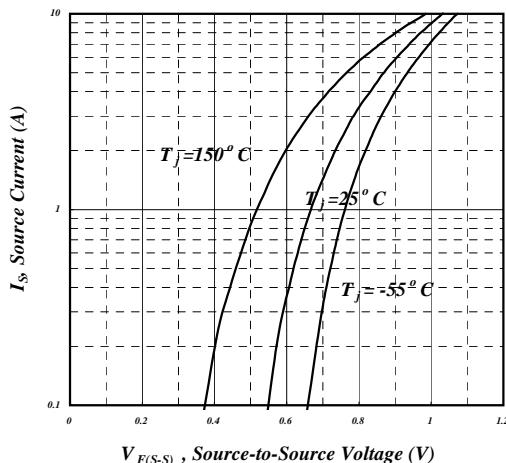


Fig 5. Forward Characteristic of Reverse Diode

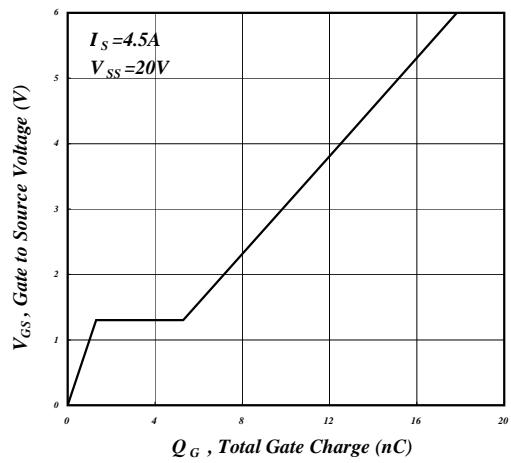


Fig 6. Gate Charge Characteristics

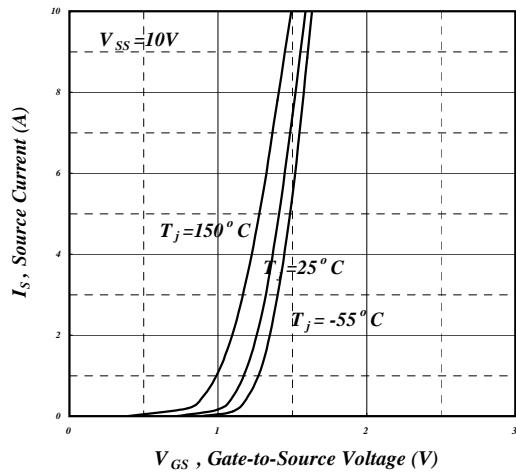


Fig 7. Transfer Characteristics



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MARKING INFORMATION

